

# BUX10

## HIGH POWER NPN SILICON TRANSISTOR

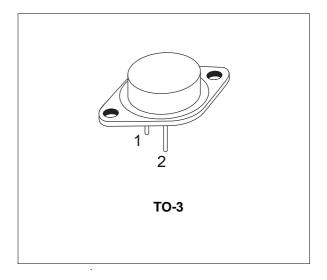
- STMicroelectronics PREFERRED SALESTYPE
- NPN TRANSISTOR
- HIGH CURRENT CAPABILITY
- FAST SWITCHING SPEED

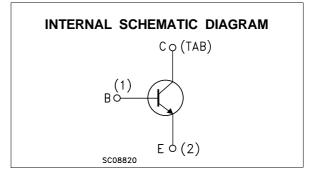
#### APPLICATIONS

- MOTOR CONTROL
- LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT

#### DESCRIPTION

The BUX10 is a silicon Multi-Epitaxial Planar NPN transistor in Jedec TO-3 metal case, intended for use in switching and linear applications in military and industrial equipment.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
Vсво	Collector-base Voltage $(I_E = 0)$	160	V
V <sub>CEX</sub>	Collector-emitter Voltage (V <sub>BE</sub> = - 1.5V)	160	V
V <sub>CEO</sub>	Collector-emitter Voltage $(I_B = 0)$	125	V
V <sub>EBO</sub>	Emitter-base Voltage (I <sub>C</sub> = 0)	7	V
lc	Collector Current	25	А
Ісм	Collector Peak Current (t <sub>P</sub> < 10 ms)	30	А
Ι <sub>Β</sub>	Base Current	5	А
Ptot	Total Power Dissipation at $T_{case} \leq 25 \ ^{\circ}C$	150	W
T <sub>stg</sub>	Storage Temperature	-65 to 200	°C
Tj	Max Operating Junction Temperature	200	°C

#### THERMAL DATA

Rthj-case Thermal Resistance Junction-case Max	1.17	°C/W
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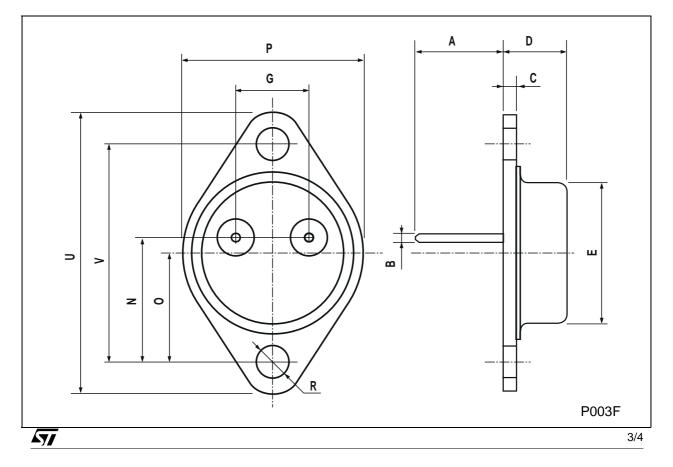
### **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25 \ ^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
ICEO	Collector Cut-off Current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 100 V				1.5	mA
I <sub>CEX</sub>	Collector Cut-off Current	$V_{CE} = 160 V$ $T_{case} = 125 °C$ $V_{CE} = 160 V$	V <sub>BE</sub> = -1.5V V <sub>BE</sub> = -1.5V			1.5 6	mA mA
I <sub>EBO</sub>	Emitter Cut-off Current $(I_c = 0)$	V <sub>EB</sub> = 5 V				1	mA
$V_{CEO(sus)^*}$	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 200 mA		125			V
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 50 mA		7			V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 10 A I <sub>C</sub> = 20 A	I <sub>B</sub> = 1 A I <sub>B</sub> = 2 A		0.3 0.7	0.6 1.2	V V
$V_{BE(sat)^*}$	Base-Emitter Saturation Voltage	I <sub>C</sub> = 20 A	I <sub>B</sub> = 2 A		1.6	2	V
h <sub>FE</sub>	DC Current Gain	$I_{C} = 10 \text{ A}$ $I_{C} = 20 \text{ A}$	V <sub>CE</sub> = 2 V V <sub>CE</sub> = 4 V	20 10		60	
I <sub>S/b</sub>	Second Breakdown Collector Current	V <sub>CE</sub> = 30 V V <sub>CE</sub> = 48 V	t = 1 s t = 1 s	5 1			A A
f⊤	Transistor Frequency	$I_{C} = 1 A$ f = 10MHz	$V_{CE}$ =15 V	8			MHz
t <sub>on</sub>	Turn-on Time	I <sub>C</sub> = 20 A V <sub>CC</sub> = 30V	I <sub>B1</sub> = 2 A		0.5	1.5	μs
t <sub>s</sub> t <sub>f</sub>	Storage Time Fall Time	$I_C = 20 \text{ A}$ $V_{CC} = 30 \text{V}$	$I_{B1} = -I_{B2} = 2A$		0.6 0.15	1.2 0.3	μs μs
	Clamped E <sub>s/b</sub> Collector Current	V <sub>clamp</sub> =125 V L = 500 μH		20			A

\* Pulsed: Pulse duration =  $300\mu s$ , duty cycle  $\leq 2 \%$ 

**TO-3 MECHANICAL DATA** 

DIM.		mm			inch	
Dim	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	11.00		13.10	0.433		0.516
В	0.97		1.15	0.038		0.045
С	1.50		1.65	0.059		0.065
D	8.32		8.92	0.327		0.351
E	19.00		20.00	0.748		0.787
G	10.70		11.10	0.421		0.437
N	16.50		17.20	0.649		0.677
Р	25.00		26.00	0.984		1.023
R	4.00		4.09	0.157		0.161
U	38.50		39.30	1.515		1.547
V	30.00		30.30	1.187		1.193



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